

IN THE CLAIMS

Please amend the claims as follows:

Claim 1 (Currently Amended): A bias voltage generating circuit, comprising:  
a first constant current generating part generating a constant current;  
a first transistor of a first conductivity type including a first current electrode to which  
a first potential is supplied through said first constant current generating part, a second  
current electrode and a control electrode; and  
a second transistor of a second conductivity type different from said first conductivity  
type including a first current electrode to which a second potential different from said first  
potential is supplied, a second current electrode connected with said second current electrode  
of said first transistor and a control electrode connected with said second current electrode of  
said first transistor, wherein  
said constant current flows between said first and second current electrodes of said  
first transistor and between said first and second current electrodes of said second transistor,  
a voltage signal is inputted to said control electrode of said first transistor from the  
exterior of said bias voltage generating circuit, and  
a potential at said second current electrode of said second transistor functions as a first  
bias voltage.

Claim 2 (Original): The bias voltage generating circuit according to claim 1, wherein  
said first constant current generating part includes  
a current source generating a current of a certain value and  
a current mirror circuit that said first potential is supplied, generating a mirror current  
of a similar value to that of said current generated in said current source and letting said

mirror current flow to said first current electrode of said first transistor as said constant current.

Claim 3 (Original): The bias voltage generating circuit according to claim 1, wherein said first constant current generating part includes a current source generating a current of a certain value, a first current mirror circuit to which said second potential is supplied, generating a first mirror current of a similar value to that of said current generated in said current source and a second current mirror circuit to which said first potential is supplied, generating a second mirror current of a similar value to that of said first mirror current and letting said second mirror current flow to said first current electrode of said first transistor as said constant current.

Claim 4 (Original): The bias voltage generating circuit according to claim 3, further comprising:

a third transistor of said first conductivity type standing between said first and second current mirror circuits and including a first and a second current electrodes and a control electrode, wherein said first mirror current flows between said first and second current electrodes of said third transistor and said voltage signal or other voltage signal is inputted to said control electrode of said third transistor.

Claim 5 (Original): The bias voltage generating circuit according to claim 1, further comprising:

a second constant current generating part generating other constant current of a similar value to that of said constant current generated in said first current generating part; a fourth transistor of said second conductivity type including a first current electrode to which said second potential is supplied through said second constant current generating part, a second current electrode and a control electrode and

a fifth transistor of said first conductivity type including a first current electrode to which said first potential is supplied, a second current electrode connected with said second current electrode of said fourth transistor and a control electrode connected with said second current electrode of said fourth transistor, wherein

said other constant current flows between said first and second current electrodes of said fourth transistor and between said first and second current electrodes of said fifth transistor,

said voltage signal is inputted to said control electrode of said fourth transistor and a potential at said second current electrode of said fifth transistor functions as a second bias voltage.

Claim 6 (Original): The bias voltage generating circuit according to claim 5, wherein said first constant current generating part includes a current source generating a current of a certain value and a first current mirror circuit to which said first potential is supplied, generating a first mirror current of a similar value to that of said current generated in said current source and letting said first mirror current flow to said first current electrode of said first transistor as said constant current, and

said second constant current generating part includes

    said current source,

    a second current mirror circuit to which said first potential is supplied and generating a second mirror current of a similar value to that of said current generated in said current source and

    a third current mirror circuit to which said second potential is supplied, generating a third mirror current of a similar value to that of said second mirror current and letting said third mirror current flow to said first current electrode of said fourth transistor as said other constant current.

Claim 7 (Original): The bias voltage generating circuit according to claim 6, further comprising:

    a sixth transistor of said first conductivity type standing between said second and third current mirror circuits and including a first and a second current electrodes and a control electrode, wherein

    said second mirror current flows between said first and second current electrodes of said sixth transistor and

    said voltage signal or other voltage signal is inputted to said control electrode of said sixth transistor.

Claim 8 (Original): The bias voltage generating circuit according to claim 1, further comprising:

    a seventh transistor of said second conductivity type including a first current electrode to which said second potential is supplied, a second current electrode and a control electrode connected with said control electrode of said second transistor;

an eighth transistor of said second conductivity type including a first current electrode connected with said second current electrode of said seventh transistor, a second current electrode and a control electrode; and

a ninth transistor of said first conductivity type including a first current electrode to which said first potential is supplied, a second current electrode connected with said second current electrode of said eighth transistor and a control electrode connected with said second current electrode of said eighth transistor, wherein

said second transistor and said seventh transistor constitute a fourth current mirror circuit,

said fourth current mirror circuit generates other constant current of a similar value to that of said constant current,

said other constant current flows between said first and second current electrodes of said eighth transistor and between said first and second current electrodes of said ninth transistor,

said voltage signal is inputted to said control electrode of said eighth transistor and a potential at said second current electrode of said ninth transistor functions as a second bias voltage.

Claim 9 (Original): A differential amplifier, comprising:

a bias voltage generating circuit according to claim 1 and

a differential amplifier circuit having a tenth transistor including a first and second current electrodes and a control electrode as a constant current circuit, wherein

a reference voltage signal and an input voltage signal are inputted to said differential amplifier circuit,

said reference voltage signal is also inputted to said control electrode of said first transistor as said voltage signal and

    said first bias voltage is inputted to said control electrode of said tenth transistor.

Claim 10 (Original): A differential amplifier, comprising:  
    a bias voltage generating circuit according to claim 5,  
    a differential amplifier circuit having an eleventh transistor of said second conductivity type including a first and second current electrodes and a control electrode as a constant current circuit and

    other differential amplifier circuit having a twelfth transistor of said first conductivity type including a first and second current electrodes and a control electrode as other constant current circuit, wherein

    both a reference voltage signal and an input voltage signal are inputted to said differential amplifier circuit and said other differential amplifier circuit, respectively,  
    said reference voltage signal is also inputted to said control electrode of said first and fourth transistors as said voltage signal, respectively,

    said first bias voltage is inputted to said control electrode of said eleventh transistor and

    said second bias voltage is inputted to said control electrode of said twelfth transistor.

Claim 11 (Original): A differential amplifier, comprising:  
    a bias voltage generating circuit according to claim 8,  
    a differential amplifier circuit having a thirteenth transistor of said second conductivity type including a first and second current electrodes and a control electrode as a constant current circuit and

other differential amplifier circuit having a fourteenth transistor of said first conductivity type including a first and second current electrodes and a control electrode as other constant current circuit, wherein

both a reference voltage signal and an input voltage signal are inputted to said differential amplifier circuit and said other differential amplifier circuit, respectively, said reference voltage signal is also inputted to said control electrode of said first and eighth transistors as said voltage signal, respectively,

said first bias voltage is inputted to said control electrode of said thirteenth transistor and

said second bias voltage is inputted to said control electrode of said fourteenth transistor.